





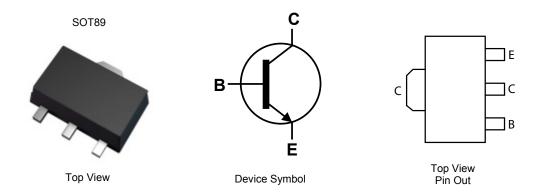
#### **45V NPN HIGH GAIN POWER TRANSISTOR IN SOT89**

#### **Features**

- BV<sub>CEO</sub> > 45V
- I<sub>C</sub> = 2A high Continuous Collector Current
- I<sub>CM</sub> up to 6A Peak Pulse Current
- High gain h<sub>FE</sub> > 400 @ 1A
- 2W Power Dissipation
- Low saturation voltage V<sub>CE(sat)</sub> < 300mV @ 1A</li>
- Complementary PNP type: FCX790A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT89
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.052 grams (Approximate)



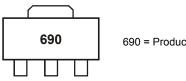
### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX690BTA	690	7	12	1,000
FCX690B-13R	690	13	12	4,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.htmlfor more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



690 = Product Type Marking Code





### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Limit	Unit
Collector-Base Voltage	$V_{CBO}$	45	V
Collector-Emitter Voltage	$V_{CEO}$	45	V
Emitter-Base Voltage	$V_{EBO}$	7	V
Continuous Collector Current	lc	2	Α
Peak Pulse Current	I <sub>CM</sub>	6	Α
Base Current	l <sub>Β</sub>	500	mA

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	D-	1	W	
Power Dissipation	(Note 6)		2	V V	
Thormal Desigtance Junction to Ambient Air	(Note 5)	0	125	00/11/	
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{\theta JA}$	62.5	°C/W	
Thermal Resistance, Junction to Leads (Note 7)		$R_{ heta JL}$	5.31	°C/W	
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C		

### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

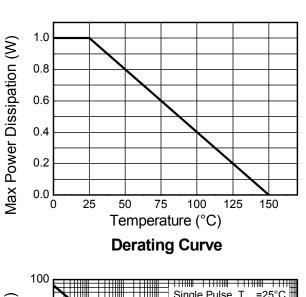
### Notes:

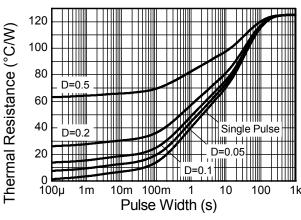
- 5. For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in steady state condition.
- 6. Same as note (5), except the device is mounted on 40mm x 40mm x 1.6mm FR4 PCB.
- 7. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

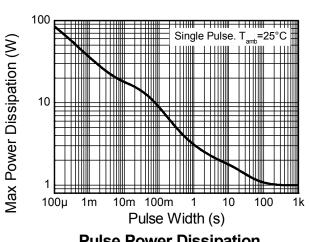




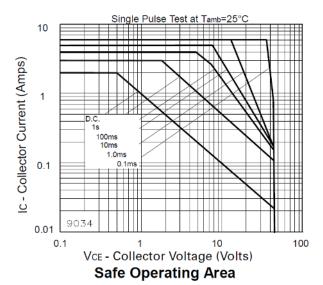
# **Thermal Characteristics and Derating Information**







**Transient Thermal Impedance** 



**Pulse Power Dissipation** 





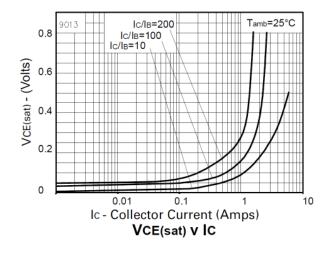
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

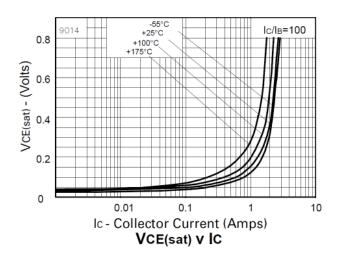
Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_CBO$	45	_	1	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	$BV_CEO$	45	_	_	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	7	_	1	V	$I_{E} = 100 \mu A$
Collector Cutoff Current	I <sub>CBO</sub>	_	_	100	nA	V <sub>CB</sub> = 35V
Emitter Cutoff Current	I <sub>EBO</sub>	_	_	100	nA	V <sub>EB</sub> = 5.6V
		500	_	-		$I_C = 100 \text{mA}, V_{CE} = 2 \text{V}$
DC current transfer Static ratio (Note 9)	h <sub>FE</sub>	400	_	_		$I_C = 1A$ , $V_{CE} = 2V$
		150	_	_		$I_C = 2A$ , $V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	_	_	80	mV	$I_C = 0.1A$ , $I_B = 0.5mA$
Collector-Entitler Saturation Voltage (Note 9)		_	_	300		$I_C = 1A, I_B = 5mA$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	_	_	0.9	V	$I_C = 1A, I_B = 10mA$
Base-Emitter Turn-on Voltage (Note 9)	$V_{BE(on)}$	_	_	0.85	V	$I_C = 1A, V_{CE} = 2V$
Transitional Frequency	$f_T$	150	-	1	MHz	$I_C$ = 50mA, $V_{CE}$ = 5V f = 50MHz
Input capacitance	$C_{ibo}$	_	200	1	pF	$V_{EB} = 0.5V, f = 1MHz,$
Output capacitance	$C_{obo}$		16	_	pF	V <sub>CB</sub> = 10V, f = 1MHz,
Switching times	t <sub>on</sub>		33		ns	$I_C = 500 \text{mA}, V_{CC} = 10 \text{V}$
Owitering times	t <sub>off</sub>		1300		115	$I_{B1} = -I_{B2} = 50 \text{mA}$

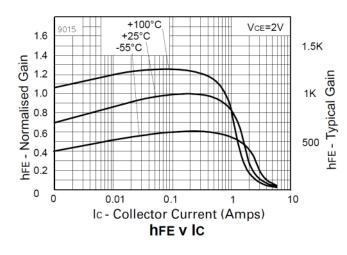
Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

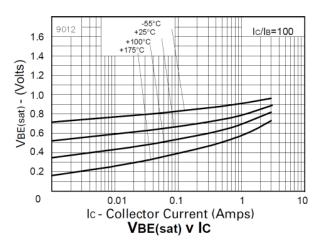


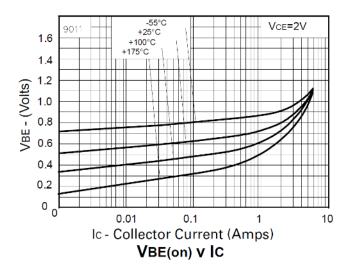
## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









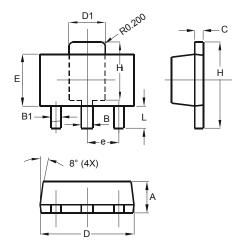






# **Package Outline Dimensions**

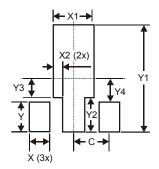
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
Е	2.29	2.60		
е	1.50 Typ			
Н	3.94 4.25			
H1	2.63 2.93			
L	0.89	1.20		
All Dimensions in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Tr.	
Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Υ	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500

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